

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	9957	(transistor mos ?mos fet mosfet ?fet ?mosfet (field adj effect) gate drain source) and (channel with (strain\$6 compress\$6 tensi\$6))	US-PGPUB	OR	ON	2007/01/26 10:00
L2	1107	(transistor mos ?mos fet mosfet ?fet ?mosfet (field adj effect) gate drain source) and (channel with (strain\$6 compress\$6 tensi\$6)) and (selectiv\$6 near2 (etch\$6 remov\$6 epitax\$6))	US-PGPUB	OR	ON	2007/01/26 10:06
L3	249	(transistor mos ?mos fet mosfet ?fet ?mosfet (field adj effect) gate drain source) and (channel with (strain\$6 compress\$6 tensi\$6)) and (selectiv\$6 near2 (etch\$6 remov\$6 epitax\$6)) and (amorphous with (silicon si))	US-PGPUB	OR	ON	2007/01/26 10:04
L4	80	(transistor mos ?mos fet mosfet ?fet ?mosfet (field adj effect) gate) and (crystal\$8 with (drain source)) and (channel with (strain\$6 compress\$6 tensi\$6)) and (selectiv\$6 near2 (etch\$6 remov\$6 epitax\$6)) and (amorphous with (silicon si))	US-PGPUB	OR	ON	2007/01/26 10:04
L5	2	((transistor mos ?mos fet mosfet ?fet ?mosfet (field adj effect) gate drain source) and (channel with (strain\$6 compress\$6 tensi\$6)) and (selectiv\$6 near2 (etch\$6 remov\$6 epitax\$6)) and (amorphous with (silicon si))).clm.	US-PGPUB	OR	ON	2007/01/26 10:04
L6	56	((transistor mos ?mos fet mosfet ?fet ?mosfet (field adj effect) gate drain source) and (channel with (strain\$6 compress\$6 tensi\$6)) and (selectiv\$6 near2 (etch\$6 remov\$6 epitax\$6))).clm.	US-PGPUB	OR	ON	2007/01/26 10:06